

PMPB33XN 30 V single N-channel Trench MOSFET 6 July 2012

**Product data sheet** 

#### **Product profile** 1.

### 1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 1.2 Features and benefits

- Trench MOSFET technology •
- Very fast switching
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- Exposed drain pad for excellent thermal conduction
- Tin-plated 100 % solderable side pads for optical solder inspection

### **1.3 Applications**

- Charging switch for portable devices •
- DC-to-DC converters •
- Power management in battery-driven portables •
- Hard disk and computing power management

### 1.4 Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	30	V
V <sub>GS</sub>	gate-source voltage			-12	-	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = 4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	[1]	-	-	5.5	А
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 4.3 A; T <sub>j</sub> = 25 °C		-	37	47	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6  $\text{cm}^2$ .



#### 30 V single N-channel Trench MOSFET

# 2. Pinning information

Table 2.	Pinning	information			
Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	D	drain		D	
2	D	drain			
3	G	gate		G	
4	S	source	3   8   4   5     Transparent top view     DFN2020MD-6 (SOT1220)		\$ 017aaa253
5	D	drain		01144255	
6	D	drain			
7	D	drain			
8	S	source			

# 3. Ordering information

Table 3.       Ordering information						
Type number	Package					
	Name	Description	Version			
PMPB33XN	DFN2020MD-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220			

# 4. Marking

Table 4. Marking codes	
Type number	Marking code
PMPB33XN	1P

# 5. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

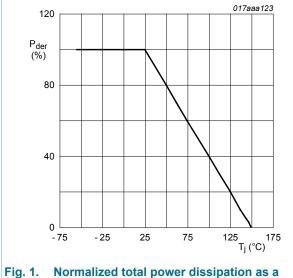
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	30	V
V <sub>GS</sub>	gate-source voltage			-12	12	V
I <sub>D</sub>	drain current	$V_{GS}$ = 4.5 V; $T_{amb}$ = 25 °C; t ≤ 5 s	[1]	-	5.5	А
		V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	4.3	А
		V <sub>GS</sub> = 4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	2.7	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	17	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[1]	-	1.5	W
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Symbol	Parameter	Conditions		Min	Мах	Unit
		T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	2.4	W
		T <sub>sp</sub> = 25 °C		-	8.3	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-dra	in diode		- I			
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	1.7	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

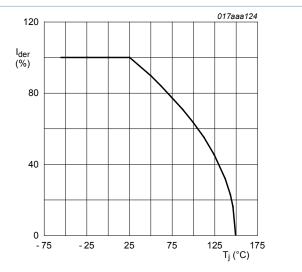


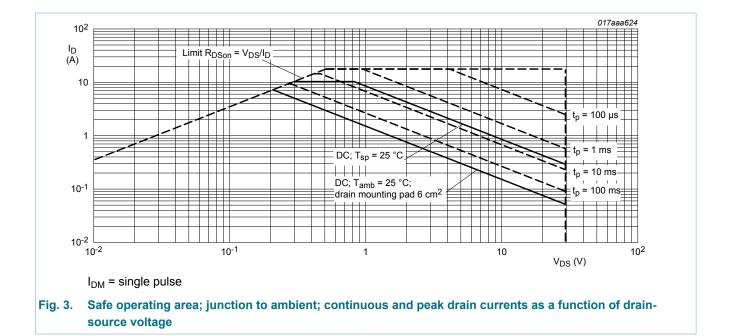
Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$

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### 6. Thermal characteristics

Table 6. Th	ermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R <sub>th(j-a)</sub> thermal resistance from junction to ambient		in free air	[1]	-	245	280	K/W
		[2]	-	74	85	K/W	
	ampient		[3]	-	45	52	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	10	15	K/W

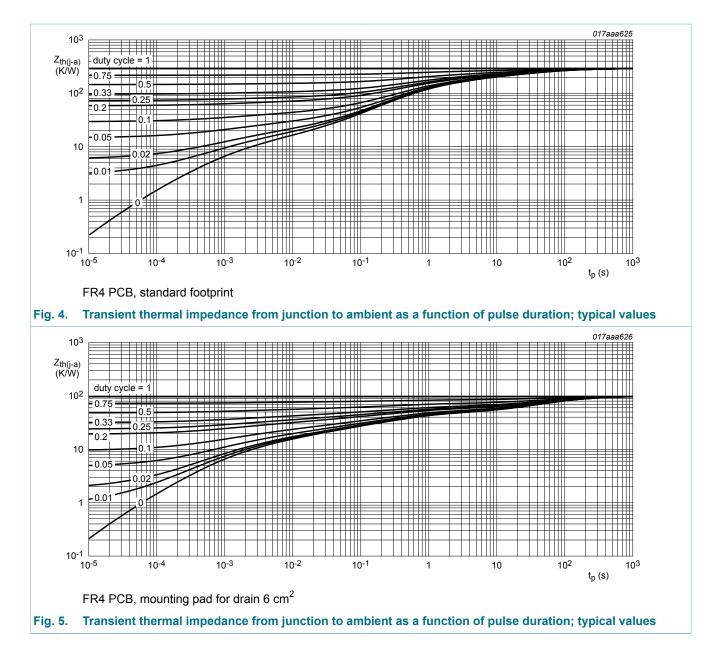
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>, t  $\leq$  5 s



#### 30 V single N-channel Trench MOSFET



# 7. Characteristics

Table 7. Cl	haracteristics						
Symbol	Parameter	Conditions	ľ	Min	Тур	Max	Unit
Static characteristics							
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = 250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	:	30	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	I <sub>D</sub> = 250 μA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 25 °C		0.45	0.8	1.2	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = 30 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	-	1	μA
		$V_{DS}$ = 30 V; $V_{GS}$ = 0 V; $T_j$ = 150 °C		-	-	100	μA
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#### 30 V single N-channel Trench MOSFET

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = 12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	100	nA
		$V_{GS}$ = -12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	100	nA
R <sub>DSon</sub>	drain-source on-state	$V_{GS}$ = 4.5 V; I <sub>D</sub> = 4.3 A; T <sub>j</sub> = 25 °C	-	37	47	mΩ
	resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 4.3 A; T <sub>j</sub> = 150 °C	-	63	80	mΩ
		$V_{GS}$ = 2.5 V; I <sub>D</sub> = 1 A; T <sub>j</sub> = 25 °C	-	55	76	mΩ
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 4.3 A; T <sub>j</sub> = 25 °C	-	20	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	9.8	-	Ω
Dynamic ch	haracteristics		l.			_,
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 15 V; I <sub>D</sub> = 4.3 A; $V_{GS}$ = 4.5 V; T <sub>j</sub> = 25 °C	-	5.1	7.6	nC
Q <sub>GS</sub>	gate-source charge		-	1	-	nC
Q <sub>GD</sub>	gate-drain charge		-	1.3	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS}$ = 15 V; f = 1 MHz; $V_{GS}$ = 0 V;	-	505	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	57	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	48	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 15 V; I <sub>D</sub> = 4.3 A; V <sub>GS</sub> = 4.5 V;	-	6	-	ns
t <sub>r</sub>	rise time	R <sub>G(ext)</sub> = 6 Ω; T <sub>j</sub> = 25 °C	-	17	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	21	-	ns
t <sub>f</sub>	fall time		-	20	-	ns

#### Source-drain diode

source-drain voltage

 $V_{SD}$ 

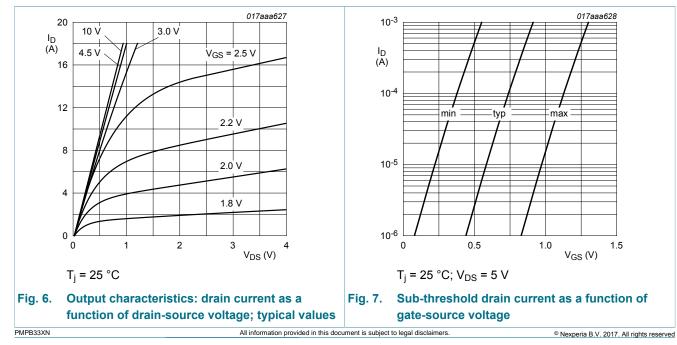
 $I_{S}$  = 1.7 A;  $V_{GS}$  = 0 V;  $T_{j}$  = 25 °C

1.2

0.8

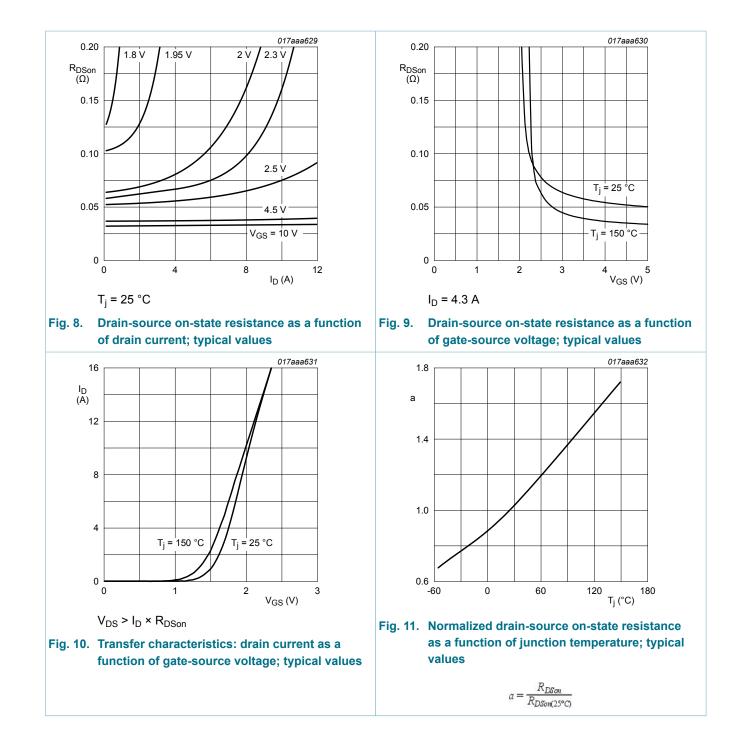
-

V



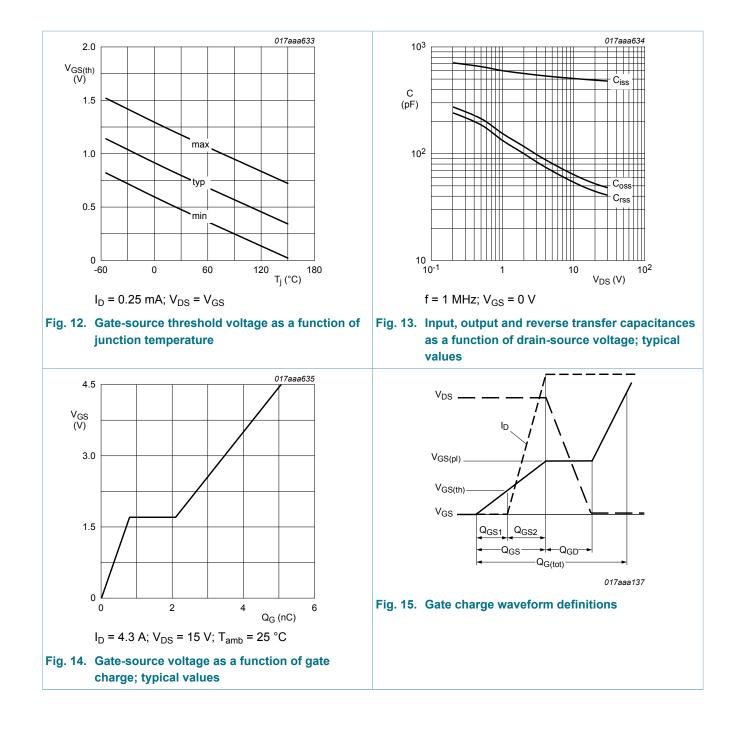
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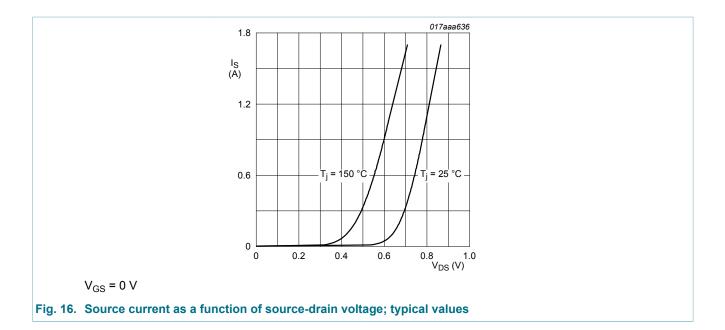
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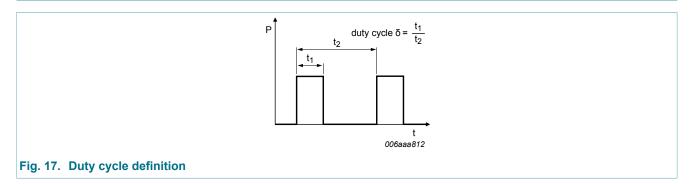


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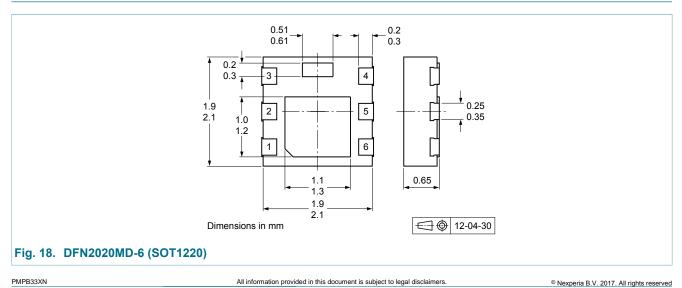
#### 30 V single N-channel Trench MOSFET



### 8. Test information

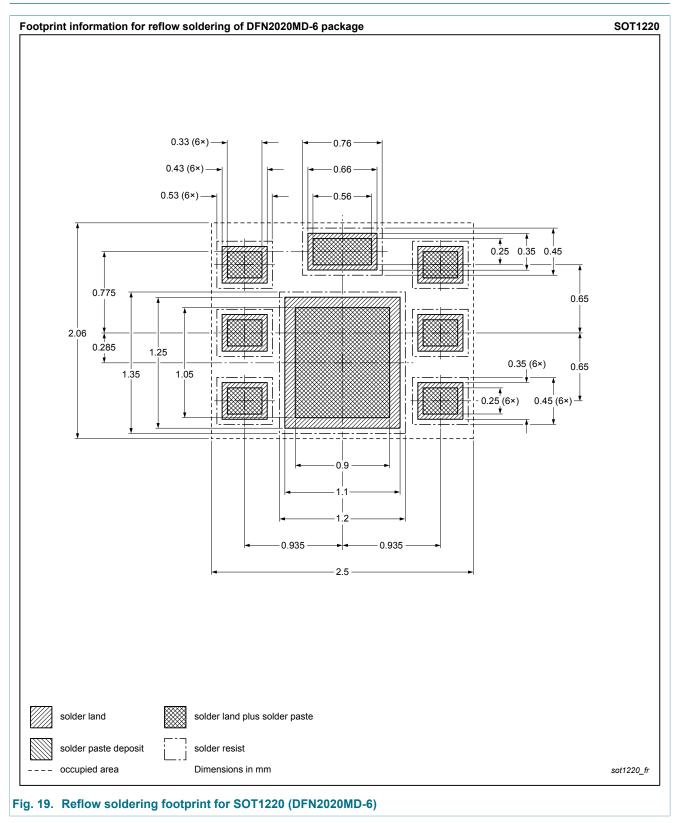


# 9. Package outline



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### **10. Soldering**



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# **11. Revision history**

Table 8.   Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes	
PMPB33XN v.1	20120706	Product data sheet	-	-	

#### 30 V single N-channel Trench MOSFET

### 12. Legal information

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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PMPB33XN

#### 30 V single N-channel Trench MOSFET

### 13. Contents

1	Product profile1
1.1	General description1
1.2	Features and benefits1
1.3	Applications1
1.4	Quick reference data1
2	Pinning information2
3	Ordering information2
4	Marking2
5	Limiting values2
6	Thermal characteristics4
7	Characteristics5
8	Test information9
9	Package outline9
10	Soldering 10
11	Revision history11
12	Legal information12
12.1	Data sheet status 12
12.2	Definitions12
12.3	Disclaimers12
12.4	Trademarks

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